

4/15/04

	L #	Hits	Search Text	DBs
1	L1	642	430/200.ccls.	USPA T; US-PG PUB
2	L2	1840	430/319,321.ccls.	USPA T; US-PG PUB
3	L3	14513 2	transfer\$4.ti,ab.	USPA T; US-PG PUB
4	L4	127	2 and 3	USPA T; US-PG PUB
5	L5	13639	black.ti,ab.	USPA T; US-PG PUB
6	L6	3	4 and 5	USPA T; US-PG PUB
7	L7	28	1 and 5	USPA T; US-PG PUB
8	L9	23399	((thermal\$4 or light or radiation or laser or heat\$4) near3 transfer\$4).ti,ab.	USPA T; US-PG PUB
9	L10	23703 2	(transistor or tft or active adj matrix or conduct\$4).ti,ab.	USPA T; US-PG PUB
10	L11	9725	(light adj shield\$4 or opaque).ti,ab.	USPA T; US-PG PUB
11	L12	42	9 and 10 and (5 or 11)	USPA T; US-PG PUB
12	L13	37	12 not (6 or 7)	USPA T; US-PG PUB
13	L14	18154 5	(thermal\$4 or light or radiation or laser or heat\$4) near3 transfer\$4	USPA T; US-PG PUB

	L #	Hits	Search Text	DBs
14	L16	40233 7	light adj shield\$4 or opaque or black	USPA T; US-PG PUB
15	L20	32406 0	transistor or tft or active adj matrix or conduct\$4 adj element	USPA T; US-PG PUB
16	L22	65	14 same 16 same 20	USPA T; US-PG PUB
17	L23	14200 1	(thermal\$4 or light or radiation or laser or heat\$4) near3 transfer\$4	EPO; JPO; DERW ENT; IBM_T DB
18	L24	21077 1	light adj shield\$4 or opaque or black	EPO; JPO; DERW ENT; IBM_T DB
19	L25	38996 5	transistor or tft or active adj matrix or conduct\$4 adj element	EPO; JPO; DERW ENT; IBM_T DB
20	L26	22	23 and 24 and 25	EPO; JPO; DERW ENT; IBM_T DB
21	L27	92642 9	transfer\$4	EPO; JPO; DERW ENT; IBM_T DB
22	L28	57	(24 with 27) and 25	EPO; JPO; DERW ENT; IBM_T DB

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23	L29	44	28 not 26	EPO; JPO; DERW ENT; IBM_T DB